# MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PLED

# 1N4001WS-1N4007WS

**Product specification** 





## **FEATURES**

- Low profile space
- Ideal for automated placement
- Glass passivated chip junctions
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High temperature soldering : 260C/10 seconds at terminals

# **Reference News**

# **MECHANICAL DATA**

- Case: SOD-323 molded plastic body over glass passivated chip
- Terminals: Solder plated, solderable per JESD22-B102
- Polarity: Laser band denotes cathode end

PACKAGE OUTLINE	Circuit	PINNING	
2		PIN	DESCRIPTION
STATISTICS OF STATISTICS		1	Cathode
1 SOD-323		2	Anode

# Maximum Ratings & Thermal Characteristics (TA = 25 °C unless otherwise noted).

Items	Symbol	1N4001WS 1 A	1N4002WS 2 A	1N4003WS 3 A	1N4004WS 4 A	1N4005WS 5A	1 N4006 WS 6 A	1N4007WS 7A	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_L = 9.0$ C	F(AV)	1					А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	25					А		
Thermal resistance from junction to lead(1)	R <sub>0 JL</sub>	35					°C / W		
Operating junction range	TJ	-55 to +150				°C			
Storage temperature range	T <sub>STG</sub>	-55 to +150			°C				

Note 1: Mounted on PCB with 0.2 x 0.2" (5.0 x 5.0mm) copper pad areas .

#### Electrical Characteristics(TA = 25 °C unless otherwise noted)

Items	Test conditions		Symbol	Min	Туре	Max	UNIT
Instantaneous forward voltage	I <sub>F</sub> =0 .5A		M		0.92	-	
5	I <sub>F</sub> = 1 A		VF	-	0.98	1.1	V
Reverse current		T <sub>A</sub> = 2 5 ℃				5	
	V <sub>R</sub> = V <sub>DC</sub>	T <sub>A</sub> = 1 2 5 ℃	IR			50	μA

Note 2: Pulse test: 3 0 0 ps pulse width, 1 % duty cycle.

# **RATING AND CHARACTERISTIC CURVES (1N4001WS THRU 1N4007WS)**

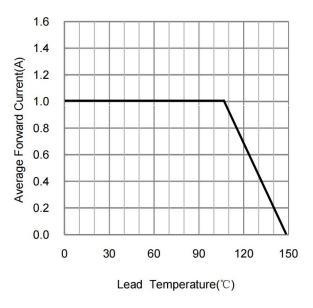


Fig.1 Forward Current Derating Curve

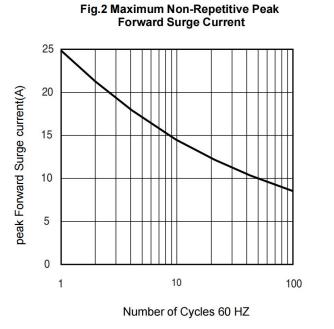


Fig.3 Typical Instantaneous Forward

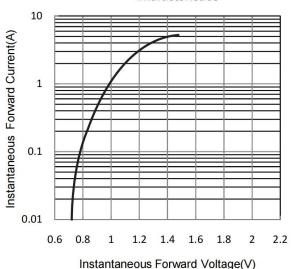
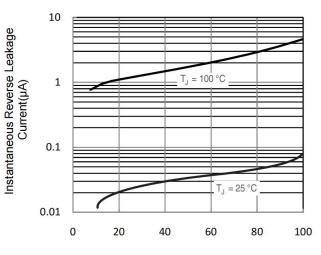


Fig.4 TypicI Reverse Leakage Characteristics

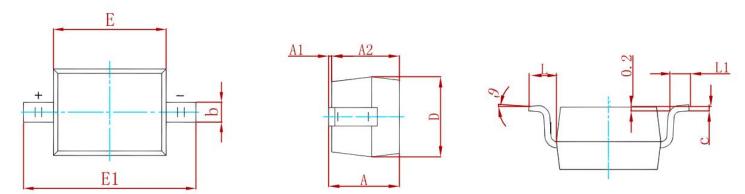


Percent Reted Peak Reverse Voltage(%)

Characteristics

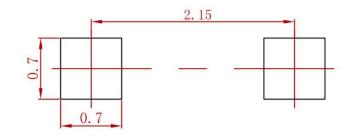


# PACKAGE MECHANICAL DATA



Symbo1	Dimensions In Millimeters		Dimensions	In Inches
Symbol	Min	Max	Min.	Max
А		1.000		0.039
A1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.031	0.035
b	0.250	0.350	0.010	0.014
С	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
Е	1.600	1.800	0.063	0.071
E1	2.550	2.750	0.100	0.108
L	0. 475	REF	0.019	9 REF
L1	0.250	0.400	0.010	0.016
θ	0 °	8 °	0 °	8 °

# Suggested Pad Layout



Note:

1.Controlling dimension: in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.

### **REEL SPECIFICATION**

P/N	PKG	QTY
1N4001WS-1N4007WS	SOD-323	3000

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